

SBL3030CT - SBL3040CT

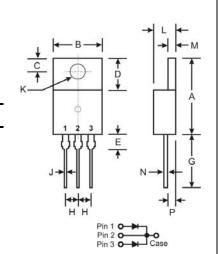
30A SCHOTTKY BARRIER RECTIFIER

Features

- Guard Ring Die Construction for **Transient Protection**
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Lead Free Finish, RoHS Compliant (Note 3)

Mechanical Data

- Case: TO-220AB
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Tin. Solderable per MIL-STD-202, Method 208 @3
- Polarity: As Marked on Body
- Marking: Type Number
- Ordering Information: See Page 3
- Weight: 2.24 grams (approximate)



| TO-220AB | | | | |
|----------------------|-------|-------|--|--|
| Dim | Min | Max | | |
| Α | 14.48 | 15.75 | | |
| В | 10.00 | 10.40 | | |
| С | 2.54 | 3.43 | | |
| D | 5.90 | 6.40 | | |
| E | 2.80 | 3.93 | | |
| G | 12.70 | 14.27 | | |
| Н | 2.40 | 2.70 | | |
| J | 0.69 | 0.93 | | |
| K | 3.54 | 3.78 | | |
| L | 4.07 | 4.82 | | |
| М | 1.15 | 1.39 | | |
| N | 0.30 | 0.50 | | |
| Р | 2.04 | 2.79 | | |
| All Dimensions in mm | | | | |

Maximum Ratings and Electrical Characteristics @T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic | Symbol | SBL 3030CT | SBL 3040CT | Unit |
|--|--|---------------|---------------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 30 | 40 | V |
| RMS Reverse Voltage | $V_{R(RMS)}$ | 21 | 28 | V |
| Average Rectified Output Current (Note 1) @ T _C = 100°C | Io | 30 | | А |
| Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load | I _{FSM} | 250 | | А |
| Forward Voltage Drop @ $I_F = 15A$, $T_C = 25^{\circ}C$ | V_{FM} | 0.55 | | V |
| Peak Reverse Current $@T_C = 25^{\circ}C$ at Rated DC Blocking Voltage $@T_C = 100^{\circ}C$ | I _{RM} | 1.0 75 | | mA |
| Typical Total Capacitance (Note 2) | C _T | 450 | | pF |
| Typical Thermal Resistance Junction to Case (Note 1) | $R_{	heta JC}$ | 1.5 | | °C/W |
| Operating Temperature Range | Tj | -55 to +125 | | °C |
| Storage Temperature Range | T _{STG} | -55 to +150 | | °C |
| Critical Rate of Rise Reverse Voltage | dv/dt | 10,000 | | V/µs |

Notes:

- Thermal resistance junction to case mounted on heatsink.
- Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- RoHS revision 13.2.2003. Glass and high temperature solder exemptions applied, see EU Directive Annex Notes 5 and 7.



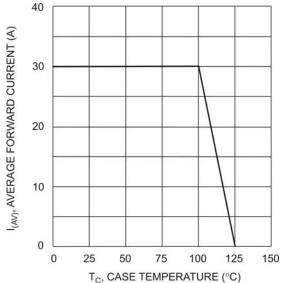
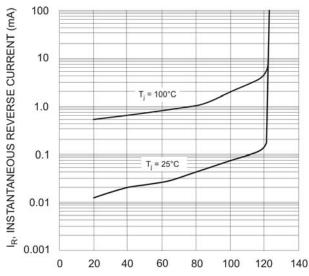


Fig. 1 Forward Current Derating Curve



PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 3 Typical Reverse Characteristics

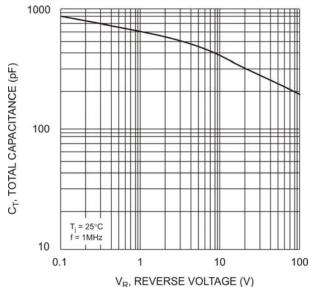
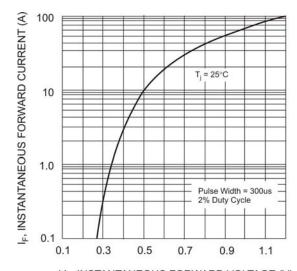


Fig. 5 Typical Total Capacitance



V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics

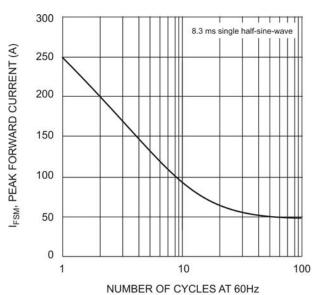


Fig. 4 Maximum Non-Repetitive Forward Surge Current



Ordering Information (Note 4)

| Device | Packaging | Shipping |
|-----------|-----------|----------|
| SBL3030CT | TO-220AB | 50/Tube |
| SBL3040CT | TO-220AB | 50/Tube |

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

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